Diode Semiconductor Device - Page 1 of 1



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Metal	
Overall L	_ength:
0.700 inc	-
Overall [Diameter:
1.000 inc	hes
Mountin	g Facility Quantity:
1	
Mountin	g Method:
Threaded	d stud
Features	Provided:
Hermetic	ally sealed case
Thread S	Size:
0.312 inc	hes
Semicon	ductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
50.0 rev	erse voltage, peak
Current	Rating Per Characteristic:
25.00 mi	croamperes forward current, average peak
Maximur	n Operating Tempurature Per Measurement Point:
150.0 de	grees celsius ambient air
Thread S	Series Designator:
Unc	
Termina	Type And Quantity:
1 case ar	nd 1 threaded stud
Shelf Lif	e:
N/a	
Unit Of M	leasure:
Demilita	rization:
No	
Fiig:	
A110a0	